MOSFET – Power, Single, N-Channel with ESD Protection, SOT-723

20 V, 890 mA

Features

- N-Channel Switch with Low R_{DS(on)}
- 44% Smaller Footprint and 38% Thinner than SC89
- Low Threshold Levels Allowing 1.5 V R_{DS(on)} Rating
- Operated at Low Logic Level Gate Drive
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Load/Power Switching
- Interface Switching
- Logic Level Shift
- Battery Management for Ultra Small Portable Electronics

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V_{DSS}	20	V
Gate-to-Source Volt	Gate-to-Source Voltage			±8	V
Continuous Drain	Steady State	T _A = 25°C	I _D	890	mA
Current (Note 1)	State	T _A = 85°C		640	
	t ≤ 5 s	T _A = 25°C		990	
Power Dissipation (Note 1)	Steady State	T _A = 25°C	P _D	450	mW
	t ≤ 5 s			550	
Continuous Drain	Steady State	T _A = 25°C	I _D	750	mA
Current (Note 2)	State	T _A = 85°C		540	
Power Dissipation (Note 2)		T _A = 25°C	P _D	310	mW
Pulsed Drain Current	t _p = 10 μs		I _{DM}	1.8	Α
Operating Junction and Storage Temperature		T _J , T _{STG}	–55 to 150	°C	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces)
- 2. Surface mounted on FR4 board using the minimum recommended pad size

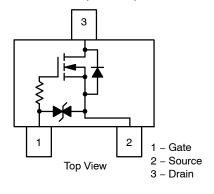


ON Semiconductor®

www.onsemi.com

V _{(BR)DSS}	R _{DS(on)} TYP	I _D Max	
20 V	0.20 Ω @ 4.5 V	890 mA	
	0.26 Ω @ 2.5 V	790 mA	
	0.43 Ω @ 1.8 V	700 mA	
	0.56 Ω @ 1.5 V	200 mA	

SOT-723 (3-LEAD)





SOT-723 CASE 631AA STYLE 5

MARKING DIAGRAM



KF = Specific Device Code M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]	
NTK3134NT1G	SOT-723	4000 / Tape & Reel	
NTK3134NT5G	SOT-723	8000 / Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 3)	$R_{ hetaJA}$	280	°C/W
Junction-to-Ambient - t = 5 s (Note 3)	$R_{ hetaJA}$	228	
Junction-to-Ambient - Steady State Minimum Pad (Note 4)	$R_{ hetaJA}$	400	

- 3. Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces)
 4. Surface mounted on FR4 board using the minimum recommended pad size

$\textbf{MOSFET ELECTRICAL CHARACTERISTICS} \ (T_J = 25^{\circ}\text{C unless otherwise specified})$

Parameter	Symbol	Test Condition Min		Min	Тур	Max	Unit
OFF CHARACTERISTICS	•			1			•
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A}$ 20				V	
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	I _D = 250 μA, Reference to 25°C			18		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 16 V				1.0	μΑ
		V _{DS} = 16 V	T _J = 125°C			2.0	1
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm$	4.5 V			±0.5	μΑ
ON CHARACTERISTICS (Note 5)				•			-
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$, $I_D = 2$	50 μΑ	0.45		1.2	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				2.4		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 890 mA			0.20	0.35	Ω
		V _{GS} = 2.5 V, I _D = 780 mA			0.26	0.45	
		V _{GS} = 1.8 V, I _D = 700 mA			0.43	0.65	1
		V _{GS} = 1.5 V, I _D = 200 mA			0.56	1.2	1
Forward Transconductance	9 _{FS}	V _{DS} = 10 V, I _D = 800 mA			1.6		S
CHARGES, CAPACITANCES AND	GATE RESISTAN	ICE					
Input Capacitance	C _{ISS}	$V_{GS} = 0 \text{ V, f} = 1 \text{ MHz, } V_{DS} = 16 \text{ V}$			79	120	pF
Output Capacitance	C _{OSS}				13	20	
Reverse Transfer Capacitance	C _{RSS}				9.0	15	
SWITCHING CHARACTERISTICS,	V _{GS} = 4.5 V (Note	e 6)					
Turn On Delay Time	t _{d(ON)}	V_{GS} = 4.5 V, V_{DS} = 10 V, I_{D} = 500 mA, R_{G} = 10 Ω			6.7		ns
Rise Time	t _r				4.8		
TurnOff Delay Time	t _{d(OFF)}				17.3		
Fall Time	t _f				7.4		
DRAIN SOURCE DIODE CHARACT	ERISTICS						
Forward Diode Voltage	V_{SD}	$V_{GS} = 0 \text{ V}, I_{S} = 350 \text{ mA}$	T _J = 25°C		0.75	1.2	V
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 \text{ V}, d_{ SD}/d_t = 1$ $I_S = 1.0 \text{ A}, V_{DD} = 1$	00 A/μs,		8.1		ns
Charge Time	t _a	I _S = 1.0 A, V _{DD} = 20 V			6.4		1
Discharge Time	t _b				1.7		
Reverse Recovery Charge	Q _{RR}				3.0		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 5. Pulse Test: pulse width = 300 μs, duty cycle = 2%
- 6. Switching characteristics are independent of operating junction temperatures

TYPICAL CHARACTERISTICS

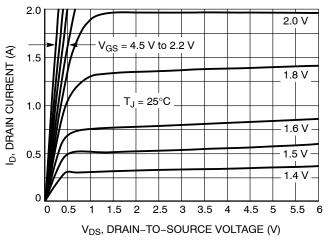


Figure 1. On-Region Characteristics

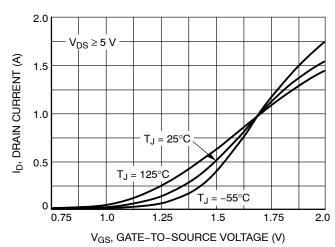


Figure 2. Transfer Characteristics

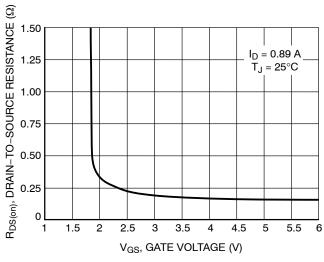


Figure 3. On-Resistance vs. Gate-to-Source Voltage

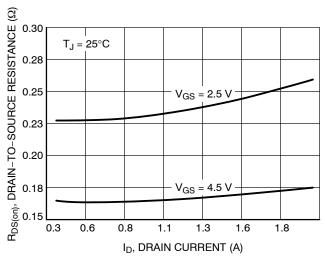


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

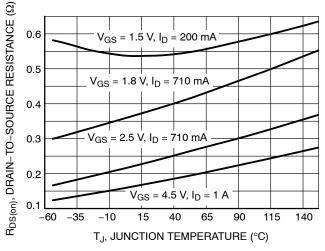


Figure 5. On–Resistance Variation with Temperature

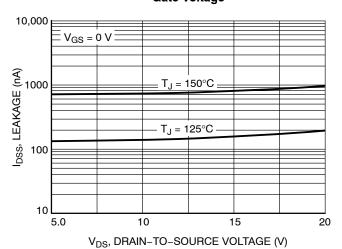


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL CHARACTERISTICS

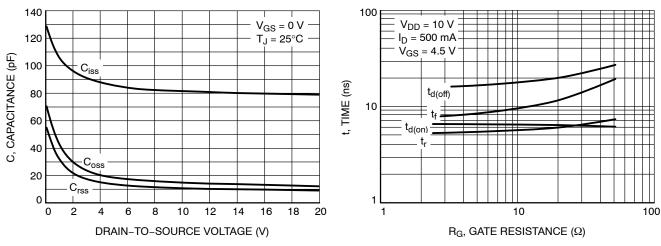


Figure 7. Capacitance Variation

Figure 8. Resistive Switching Time Variation vs. Gate Resistance

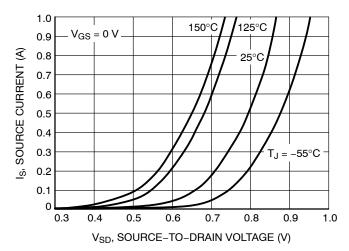


Figure 9. Diode Forward Voltage vs. Current



SOT-723 CASE 631AA-01 ISSUE D

DATE 10 AUG 2009

NOTES:

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD
- FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.45	0.50	0.55	
b	0.15	0.21	0.27	
b1	0.25	0.31	0.37	
С	0.07	0.12	0.17	
D	1.15	1.20	1.25	
E	0.75	0.80	0.85	
е	0.40 BSC			
ΗE	1.15	1.20	1.25	
L	0.29 REF			
12	0.15	0.20	0.25	

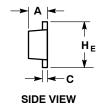
L2 0.15 0.20 0.25 **GENERIC MARKING DIAGRAM***

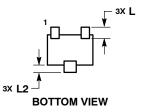


= Specific Device Code XX Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

-X-2X b ⊕ 0.08 X Y **TOP VIEW**

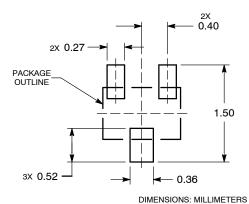




STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON12989D Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOT-723		PAGE 1 OF 1

ON Semiconductor and unare trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative